## MJ15015 and MJ15016 are Preferred Devices

## Complementary Silicon High－Power Transistors

These PowerBase ${ }^{T M}$ complementary transistors are designed for high power audio，stepping motor and other linear applications．These devices can also be used in power switching circuits such as relay or solenoid drivers，dc－to－dc converters，inverters，or for inductive loads requiring higher safe operating area than the 2 N 3055 ．

## Features

－Current－Gain－Bandwidth－Product＠ $\mathrm{I}_{\mathrm{C}}=1.0$ Adc

$$
\begin{aligned}
\mathrm{f}_{\mathrm{T}} & =0.8 \mathrm{MHz}(\mathrm{Min})-\mathrm{NPN} \\
& =2.2 \mathrm{MHz}(\mathrm{Min})-\mathrm{PNP}
\end{aligned}
$$

－Safe Operating Area－Rated to 60 V and 120 V ，Respectively
－ $\mathrm{Pb}-$ Free Packages are Available＊
MAXIMUM RATINGS（Note 1）

\left.| Rating | Symbol | Value | Unit |
| :--- | :---: | :---: | :---: |
| Collector－Emitter Voltage |  |  |  |
| MJ15015，MJ15016 |  |  |  |$\right)$

THERMAL CHARACTERISTICS

| Characteristics | Symbol | Max | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |
| Thermal Resistance，Junction－to－Case | $R_{\text {өJc }}$ | 1.52 | 0.98 | ${ }^{\circ} \mathrm{C} / \mathrm{W}$ |

Stresses exceeding Maximum Ratings may damage the device．Maximum Ratings are stress ratings only．Functional operation above the Recommended Operating Conditions is not implied．Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability．
1．Indicates JEDEC Registered Data．（2N3055A）
＊For additional information on our $\mathrm{Pb}-F r e e$ strategy and soldering details，please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual，SOLDERRM／D．

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## 15 AMPERE COMPLEMENTARY SILICON POWER TRANSISTORS 60， 120 VOLTS－115， 180 WATTS



TO－204AA（TO－3） CASE 1－07 STYLE 1

## MARKING DIAGRAMS



| 2N3055A $=$ | Device Code |
| ---: | :--- |
| MJ1501x $=$ | Device Code |
|  | $x=5$ or 6 |
| G | $=$ Pb－Free Package |
| A | $=$ Assembly Location |
| Y | $=$ Year |
| WW | $=$ Work Week |
| MEX | $=$ Country of Origin |

## ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet．

Preferred devices are recommended choices for future use and best overall value．

## 2N3055A（NPN），MJ15015（NPN），MJ15016（PNP）

ELECTRICAL CHARACTERISTICS $\left(\mathrm{T}_{\mathrm{C}}=25^{\circ} \mathrm{C}\right.$ unless otherwise noted）

| Characteristic | Symbol | Min | Max | Unit |
| :---: | :---: | :---: | :---: | :---: |

OFF CHARACTERISTICS（Note 2）

| Collector－Emitter Sustaining Voltage（Note 3） $\left(I_{C}=200 \mathrm{mAdc}, \mathrm{I}_{\mathrm{B}}=0\right)$ | 2N3055A MJ15015，MJ15016 | $\mathrm{V}_{\text {CEO（sus）}}$ | $\begin{gathered} 60 \\ 120 \end{gathered}$ | － | Vdc |
| :---: | :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { Collector Cutoff Current } \\ & \left.\qquad \begin{array}{l} \left.\mathrm{V}_{\mathrm{CE}}=30 \mathrm{Vdc}, \mathrm{~V}_{\mathrm{BE}(\text { off })}=0 \mathrm{Vdc}\right) \\ \left(\mathrm{V}_{\mathrm{CE}}=60 \mathrm{Vdc}, \mathrm{~V}_{\mathrm{BE}} \text { (off) }\right) \end{array}=0 \mathrm{Vdc}\right) \end{aligned}$ | 2N3055A MJ15015，MJ15016 | ICEO | － | $\begin{aligned} & 0.7 \\ & 0.1 \end{aligned}$ | mAdc |
| Collector Cutoff Current（Note 3） $\left(\mathrm{V}_{\mathrm{CEV}}=\text { Rated Value, } \mathrm{V}_{\mathrm{BE}(\text { off })}=1.5 \mathrm{Vdc}\right)$ | $\begin{array}{r} \text { 2N3055A } \\ \text { MJ15015, MJ15016 } \end{array}$ | $\mathrm{I}_{\text {cev }}$ | － | $\begin{aligned} & 5.0 \\ & 1.0 \end{aligned}$ | mAdc |
| $\begin{aligned} & \text { Collector Cutoff Current } \\ & \left(\mathrm{V}_{\mathrm{CEV}}=\text { Rated Value, } \mathrm{V}_{\mathrm{BE}(\text { off })}=1.5 \mathrm{Vdc}\right. \text {, } \\ & \left.\mathrm{T}_{\mathrm{C}}=150^{\circ} \mathrm{C}\right) \end{aligned}$ | 2N3055A MJ15015，MJ15016 | $I_{\text {CEV }}$ | － | $\begin{aligned} & 30 \\ & 6.0 \end{aligned}$ | mAdc |
| Emitter Cutoff Current $\left(\mathrm{V}_{\mathrm{EB}}=7.0 \mathrm{Vdc}, \mathrm{I}_{\mathrm{C}}=0\right)$ | $\begin{array}{r} \text { 2N3055A } \\ \text { MJ15015, MJ15016 } \end{array}$ | $\mathrm{I}_{\text {Ebo }}$ | － | $\begin{aligned} & 5.0 \\ & 0.2 \end{aligned}$ | mAdc |

SECOND BREAKDOWN（Note 3）

| Second Breakdown Collector Current with Base Forward Biased $\begin{gathered} (\mathrm{t}=0.5 \mathrm{~s} \text { non-repetitive }) \\ \left(\mathrm{V}_{\mathrm{CE}}=60 \mathrm{Vdc}\right) \end{gathered}$ MJ15015, MJ15016 | $\mathrm{I}_{\text {S／b }}$ | $\begin{gathered} 1.95 \\ 3.0 \end{gathered}$ | － | Adc |
| :---: | :---: | :---: | :---: | :---: |

ON CHARACTERISTICS（Note 2 and 3）

| $\begin{aligned} & \text { DC Current Gain } \\ & \left(\mathrm{I}_{\mathrm{C}}=4.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=2.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=4.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=4.0 \mathrm{Vdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=4.0 \mathrm{Vdc}\right) \end{aligned}$ | $\mathrm{h}_{\text {FE }}$ | $\begin{aligned} & 10 \\ & 20 \\ & 5.0 \end{aligned}$ | $\begin{aligned} & 70 \\ & 70 \\ & - \end{aligned}$ |  |
| :---: | :---: | :---: | :---: | :---: |
| $\begin{aligned} & \text { Collector-Emitter Saturation Voltage } \\ & \left(I_{C}=4.0 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=400 \mathrm{mAdc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=10 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=3.3 \mathrm{Adc}\right) \\ & \left(\mathrm{I}_{\mathrm{C}}=15 \mathrm{Adc}, \mathrm{I}_{\mathrm{B}}=7.0 \mathrm{Adc}\right) \end{aligned}$ | $\mathrm{V}_{\text {CE（sat）}}$ | － | $\begin{aligned} & 1.1 \\ & 3.0 \\ & 5.0 \end{aligned}$ | Vdc |
| Base－Emitter On Voltage $\left(\mathrm{I}_{\mathrm{C}}=4.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=4.0 \mathrm{Vdc}\right)$ | $\mathrm{V}_{\mathrm{BE} \text {（on）}}$ | 0.7 | 1.8 | Vdc |

DYNAMIC CHARACTERISTICS（Note 3）

| Current－Gain－Bandwidth Product $\left(\mathrm{I}_{\mathrm{C}}=1.0 \mathrm{Adc}, \mathrm{~V}_{\mathrm{CE}}=4.0 \mathrm{Vdc}, \mathrm{f}=1.0 \mathrm{MHz}\right)$ | 2N3055A，MJ15015 MJ15016 | $\mathrm{f}_{\mathrm{T}}$ | $\begin{aligned} & 0.8 \\ & 2.2 \end{aligned}$ | $\begin{aligned} & 6.0 \\ & 18 \end{aligned}$ | MHz |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Output Capacitance $\left(\mathrm{V}_{\mathrm{CB}}=10 \mathrm{Vdc}, \mathrm{I}_{\mathrm{E}}=0, \mathrm{f}=1.0 \mathrm{MHz}\right)$ |  | $\mathrm{C}_{\text {ob }}$ | 60 | 600 | pF |

SWITCHING CHARACTERISTICS（2N3055A only）（Note 3）


2．Pulse Test：Pulse Width $=300 \mu \mathrm{~s}$ ，Duty Cycle $\leq 2 \%$ ．
3．Indicates JEDEC Registered Data．（2N3055A）

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## 2N3055A（NPN），MJ15015（NPN），MJ15016（PNP）



Figure 1．Power Derating

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Figure 2．DC Current Gain

Figure 4．＂On＂Voltages


Figure 3．Collector Saturation Region


Figure 5．Current－Gain－Bandwidth Product

## 2N3055A（NPN），MJ15015（NPN），MJ15016（PNP）



Figure 6．Switching Times Test Circuit （Circuit shown is for NPN）

Figure 8．Turn－Off Times


Figure 7．Turn－On Time


Figure 9．Capacitances

# 2N3055A（NPN），MJ15015（NPN），MJ15016（PNP） <br> COLLECTOR CUT－OFF REGION 



Figure 10．2N3055A，MJ15015

$\mathrm{V}_{\mathrm{CE}}$ ，COLLECTOR－EMITTER VOLTAGE（VOLTS）
Figure 12．Forward Bias Safe Operating Area 2N3055A

There are two limitations on the power handling ability of a transistor：average junction temperature and second breakdown．Safe Operating area curves indicate $I_{C}-V_{C E}$ limits of the transistor that must be observed for reliable operation；i．e．，the transistor must not be subjected to greater dissipation than the curves indicate．

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Http：／／www．100y．com．tw

ORDERING INFORMATION

| Device | Package | Shipping |
| :--- | :---: | :---: |
| 2N3055A | TO－204 |  |
| 2N3055AG | TO－204 | 100 Units／Tray |
| MJ15015 | TO－204 |  |
| MJ15015G | TO－204 |  |
| MJ15016 | （Pb－Free） |  |
| MJ15016G | TO－204 |  |

## 2N3055A（NPN），MJ15015（NPN），MJ15016（PNP）

## PACKAGE DIMENSIONS

TO－204（TO－3）
CASE 1－07
ISSUE Z


NOTES：
1．DIMENSIONING AND TOLERANCING PER ANS Y14．5M， 1982.
2．CONTROLLING DIMENSION：INCH．
3．ALL RULES AND NOTES ASSOCIATED WITH REFERENCED TO－204AA OUTLINE SHALL APPLY

| DIM | INCHES |  | MILLIMETERS |  |
| :---: | :---: | :---: | :---: | :---: |
|  | MIN | MAX | MIN | MAX |
| A | 1.550 REF |  | 39．37 REF |  |
| B | －－－ | 1.050 | －－－ | 26.67 |
| C | 0.250 | 0.335 | 6.35 | 8.51 |
| D | 0.038 | 0.043 | 0.97 | 1.09 |
| E | 0.055 | 0.070 | 1.40 | 1.77 |
| G | 0.430 BSC |  | 10.92 BSC |  |
| H | 0.215 BSC |  | 5.46 BSC |  |
| K | 0.440 | 0.480 | 11.18 | 12.19 |
| L | 0.665 BSC |  | 16.89 BSC |  |
| N | －－－ | 0.830 | －－－ | 21.08 |
| Q | 0.151 | 0.165 | 3.84 | 4.19 |
| U | 1．187 BSC |  | 30.15 BSC |  |
| V | 0.131 | 0.188 | 3.33 | 4.77 |

STYLE 1：
PIN 1．BASE
2．EMITTER
CASE：COLLECTOR

> 勝 特 力 材 料 $886-3-5753170$
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> 胜特力电子(深圳) $86^{-755-83298787}$
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